## NSN 5961-01-170-7623

**Fiig:** A110a0

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View Online at https://aerobasegroup.com/nsn/5961-01-170-7623 **Inclosure Material:** Ceramic **Overall Length:** Between 0.760 inches and 0.785 inches **Terminal Length:** 0.120 inches **Overall Height:** 0.200 inches **Overall Width:** Between 0.220 inches and 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage/static/base open all transistor and 60.0 collector to base voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 0.65 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No